	Application No. Applicant(s)		
Notice of Allowability	10/705,504	MATHEW ET AL.	
	Examiner	Art Unit	
	Tu-Tu Ho	2818	
The MAILING DATE of this communication appe All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85) NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RI	(OR REMAINS) CLOSED ir or other appropriate commu GHTS. This application is s	this application. If not included inication will be mailed in due cou	rse. THIS
1. This communication is responsive to Paper filed 11/10/200	<u>3</u> .		
2. ⊠ The allowed claim(s) is/are <u>1-20</u> .			
3. A The drawings filed on 10 November 2003 are accepted by	the Examiner.		
4. ☐ Acknowledgment is made of a claim for foreign priority un a) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONM THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.	been received. been received in Application cuments have been received	n No I in this national stage application	
 A SUBSTITUTE OATH OR DECLARATION must be submi INFORMAL PATENT APPLICATION (PTO-152) which give 	itted. Note the attached EXA es reason(s) why the oath or	AMINER'S AMENDMENT or NOT declaration is deficient.	ICE OF
 6. CORRECTED DRAWINGS (as "replacement sheets") must be submitted. (a) including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date Identifying Indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d). 7. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL. 			
 Attachment(s) 1. ☑ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☑ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date 11/10/2003 & 01/04 4. ☐ Examiner's Comment Regarding Requirement for Deposit of Biological Material 	6. Interview S Paper No. 98), 7. Examiner's	ner	·

DETAILED ACTION

Allowable Subject Matter

1. Claims 1-20 are allowable over the prior art of record.

The following is an examiner's statement of reasons for allowance: The prior art of record fails to teach or render obvious an integrated circuit having a first memory and a second memory and a method for implementing thereof with all exclusive limitations as recited in claims 1, 7, and 15, characterized in that: the first memory is a non-volatile memory, the second memory is a volatile memory, each of the non-volatile and volatile memory comprises charge storing transistors, each of the transistors comprises three gate electrodes surrounding a channel, and at least one charge storage structure surrounds the channel and at least one of the three gate electrodes; or that the first memory and the second memory are formed at different locations of a same substrate with a same process, each of the first memory cell and the second memory cell includes a semiconductor structure, the semiconductor structure comprises a top surface, a first sidewall, and a second sidewall opposing the first sidewall, a first charge storage structure formed adjacent the first sidewall of the semiconductor structure of the first memory and a gate structure formed adjacent the first charge storage structure on an opposite side of the first charge storage structure from the first sidewall of the semiconductor structure of the first memory, and a second charge storage structure located over the top surface of the semiconductor structure of the second memory.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

- 2. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Copies of the references are not being furnished with this Office Action per MPEP § 707.05(a).
- U.S. Patent 6,580,124 to Cleeves et al. discloses a multi-bit nonvolatile memory cell comprising a column surrounded by four channels and four charge storage layers.
- 3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Tu-Tu Ho whose telephone number is (571) 272-1778. The examiner can normally be reached on 6:30 am 5:00 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, DAVID NELMS can be reached on (571) 272-1787. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR

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system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Tu-Tu Ho

August 30, 2004

David Nelms

Supervisory Patent Examiner Technology Center 2800